## NSN 5961-01-589-8009

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Plastic
End Application:
Mrap; rg33 haga plus
Mounting Method:
Press fit
Voltage Rating In Volts Per Characteristic:
12.0 forward voltage, dc and 24.0 forward voltage, dc
Current Rating Per Characteristic:
6.00 amperes forward current, dc
Special Features:
Operating temperature rating is minus 40.0 degrees celsius and 125.0 degrees celsius; diode has an integral key for polarity
Terminal Type And Quantity:
2 knife blade
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0
N/a Unit Of Measure: Demilitarization: No Fiig: